## NSN 5961-01-390-2501

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-390-2501 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **End Application:** Used m1a2 tank **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-48 **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.544 inches and 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.0 forward voltage, peak and 3.0 gate trigger voltage, dc and 720.0 reverse voltage, peak **Current Rating Per Characteristic:** 80.00 milliamperes forward current, total rms preset **Special Features:** Junction pattern arrangement: pnpn **Nuclear Hardness Critical Feature:** Hardened **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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